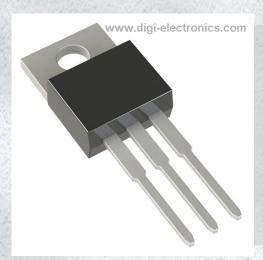


IXTP1N100 Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number IXTP1N100-DG

Manufacturer IXYS

Manufacturer Product Number IXTP1N100

Description MOSFET N-CH 1000V 1.5A TO220AB

Detailed Description N-Channel 1000 V 1.5A (Tc) 54W (Tc) Through Hole

TO-220-3



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RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
IXTP1N100	IXYS
Series:	Product Status:
-	Not For New Designs
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
1000 V	1.5A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ ld, Vgs:
10V	110hm @ 1A, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
4.5V @ 25μA	14.5 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±30V	400 pF @ 25 V
FET Feature:	Power Dissipation (Max):
	54W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Through Hole
Supplier Device Package:	Package / Case:
TO-220-3	TO-220-3
Base Product Number:	
IXTP1	

Environmental & Export classification

8541.29.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



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